





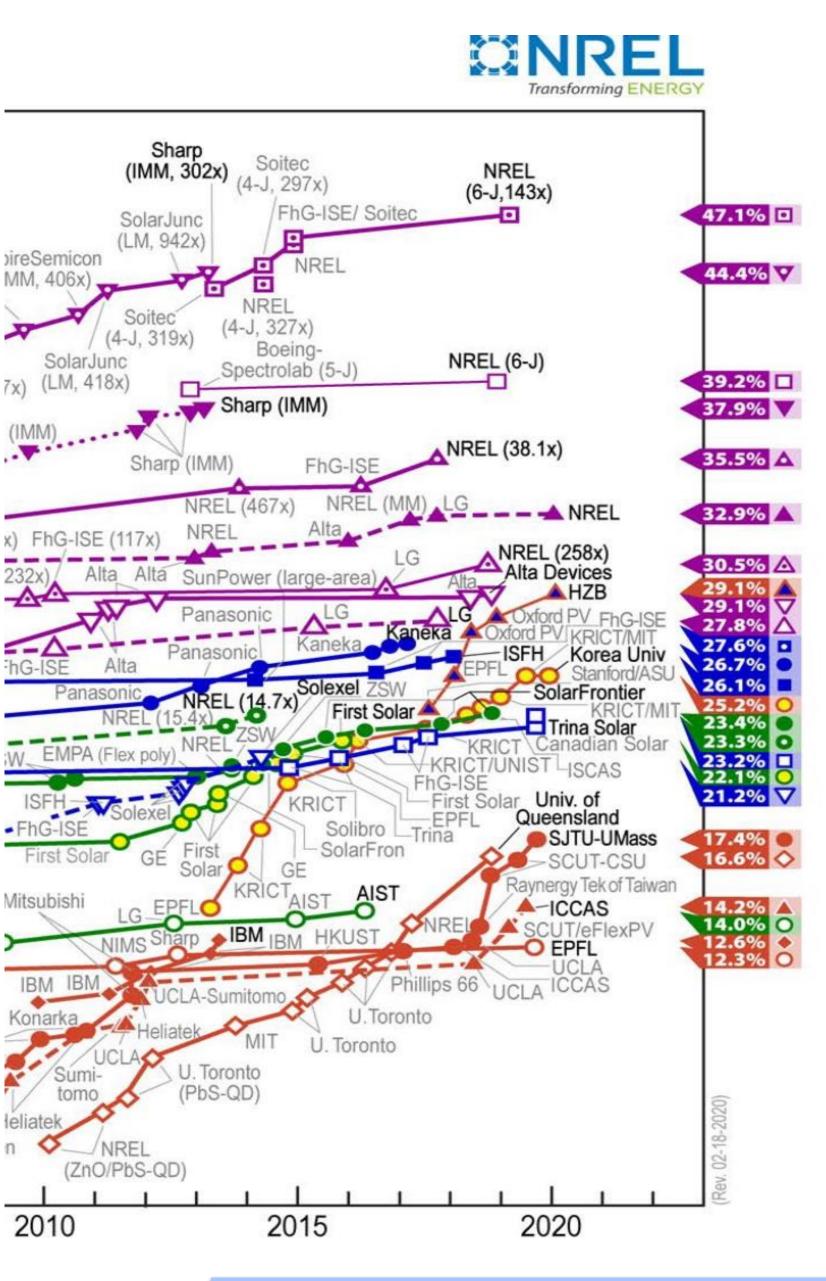


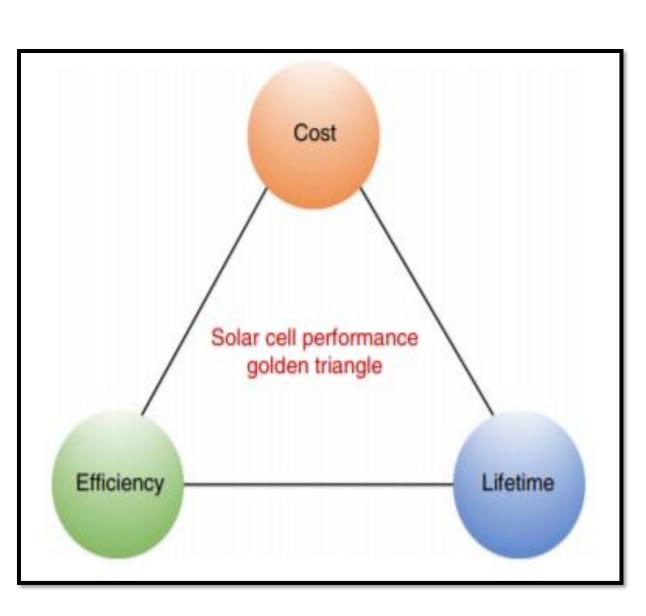
ENHANCING PERFORMANCE AND STABILITY OF PEROVSKITE SOLAR CELLS THROUGH INTERFACE ENGINEERING

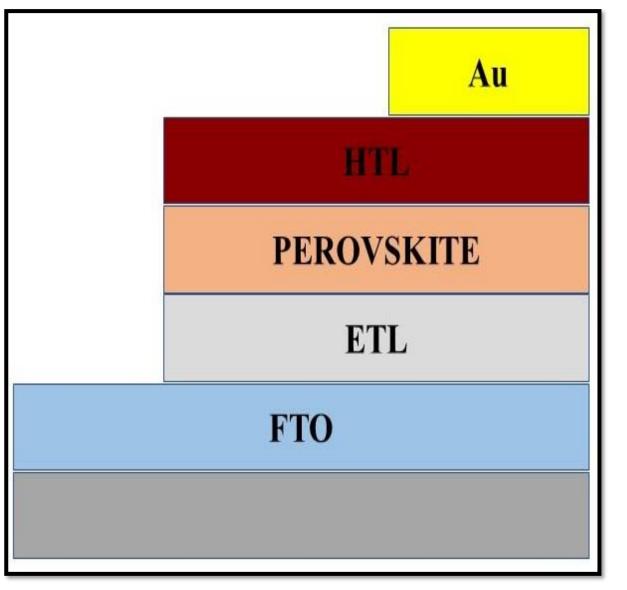
Rajeev Ray, Abdus Salam Sarkar, and Suman Kalyan Pal

**Perovskites** materials are described by the formula ABX3, where X is an anion and A and B are cations.

- High efficiency; with an efficiency more than 23% after only several years work.
- Facile low temperature solution-based fabrication method;
- High absorption coefficient.
- High diffusion length, high charge-carrier mobilities



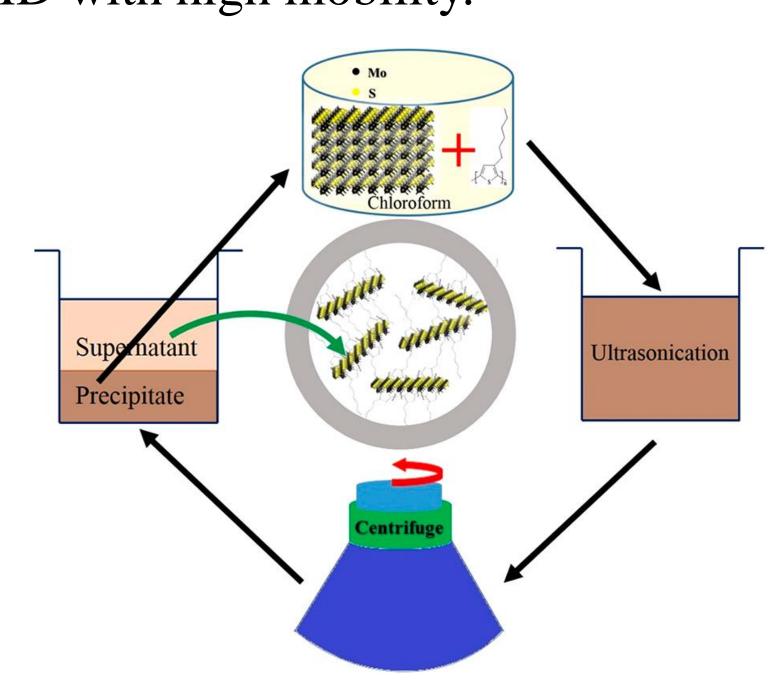




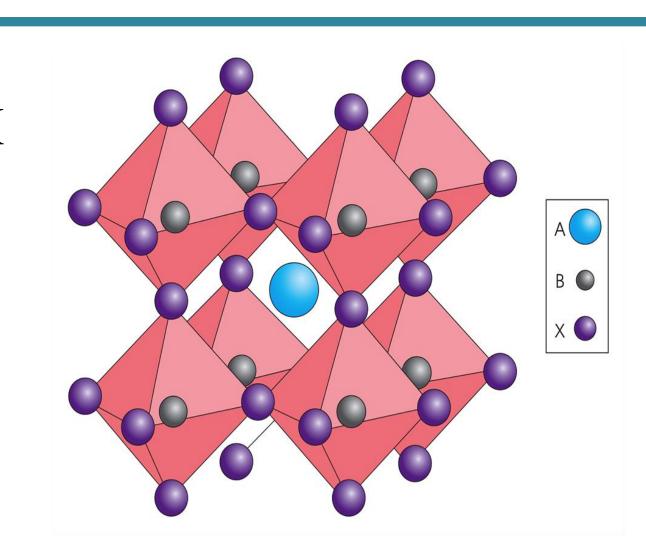
# Synthesis of P3HT-MoS<sub>2</sub>

•P3HT: High electrical conductivity and solubility.

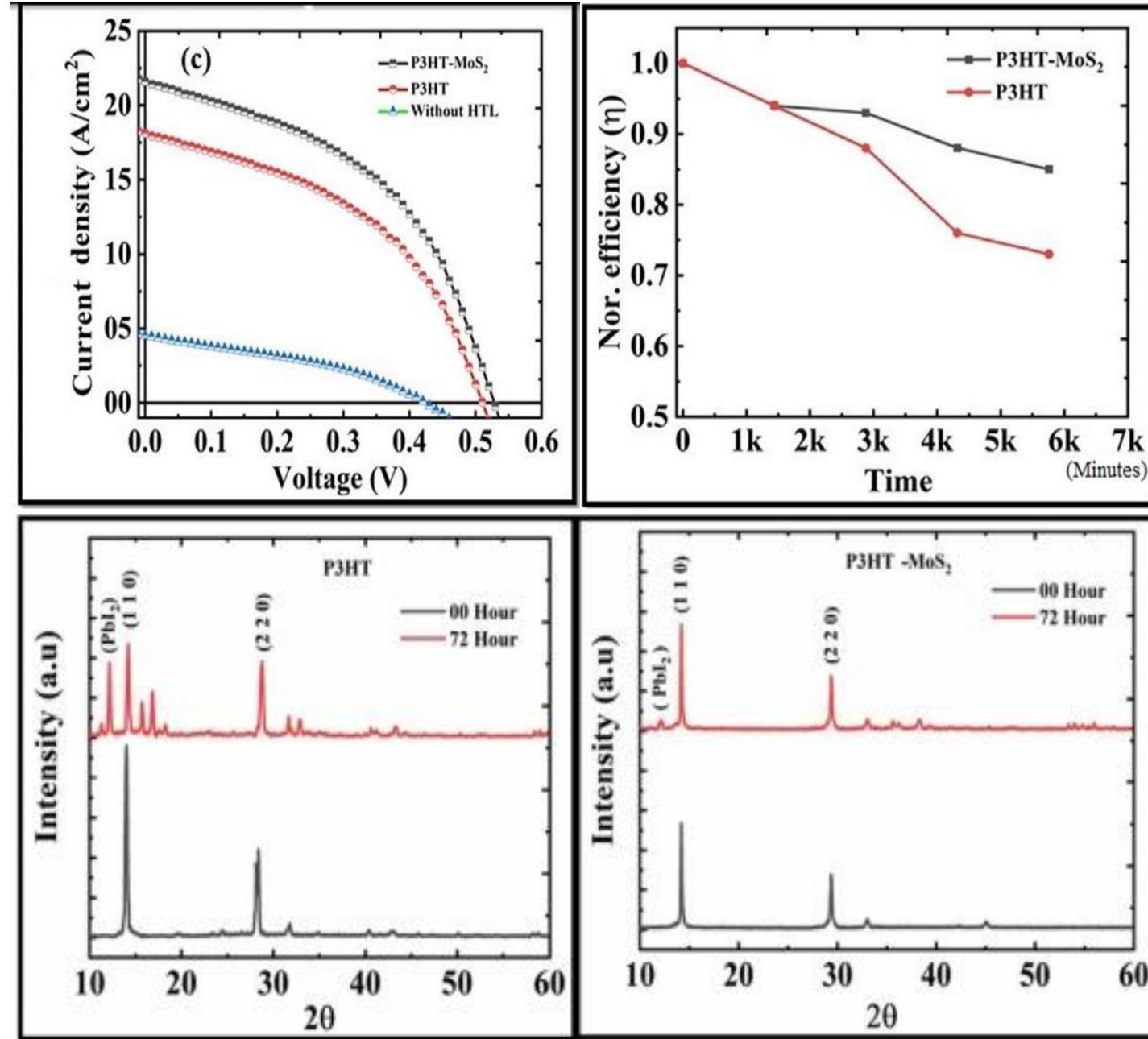
•MoS<sub>2</sub>: 2D TMD with high mobility.



- ☐ Polymer grafted MoS₂ were synthesized according to route adapted by Pal et.al.
- $\square$  Bulk MoS<sub>2</sub> was dissolved in of chloroform in a Nitrogen sealed bottle at room temperature followed by magnetic stirring.
- ☐ The nanohybrid obtained show hole mobility enhance by two order  $(1.93 \times 10^{-1} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1})$ .



## Results



Device HTL	V <sub>oc</sub> (V)	J <sub>SC</sub> (mA/cm <sup>2</sup> )	FF (%)	PCE (%)
P3HT-MoS <sub>2</sub>	0.53	21.3	64	7.2
P3HT	0.48	17.4	60	5.1
No	0.42	4.2	38	0.7

Mobility enhancement of nanohybrid from pristine P3HT thin film

Stability improvement by reducing degradation perovskite layer

## Conclusions

- We have addressed the matter of moisture stability of perovskite solar cells through interface engineering.
- The use of polymer grafted 2D MoS2 as HTL drastically improves the device stability.
- The incorporation of 2D MoS2 increase both JsC and FF by improving extraction of charge carriers leading to 41% increment in PCE.

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#### REFERENCES

E. J Yoo, M. Lyu, J. H. Yun, C. J Kang, Y. J. Choi, L. Wang, Adv. Mater. 27, 6303 (2015).
 A. Djurišić; F. Liu, H. Tam, M. Wong, C. Surya, W. Chen, Z. He. Prog. in Quantum Elect. 53, 1 (2017).
 R. Ray, A. S. Sarkar, S. K. Pal, Sol. Energy. 193, 95-101 (2019).

### ACKNOWLEDGEMEN

Rajeev Ray is thankful to IIT Mandi for its fellowship and Advanced Materials Research Centre for the experimental facilities.

